

NCE N-Channel Super Trench II Power MOSFET

Description

The series of devices uses **Super Trench II** technology that is uniquely optimized to provide the most efficient high frequency switching performance. Both conduction and switching power losses are minimized due to an extremely low combination of $R_{\text{DS(ON)}}$ and Q_g . This device is ideal for high-frequency switching and synchronous rectification.

Application

- DC/DC Converter
- ●Ideal for high-frequency switching and synchronous rectification

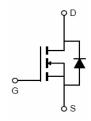
General Features

- V_{DS} =120V, I_D =65A $R_{DS(ON)}$ =8.7m Ω , typical @ V_{GS} =10V
- Excellent gate charge x R_{DS(on)} product(FOM)
- Very low on-resistance R_{DS(on)}
- 175 °C operating temperature
- Pb-free lead plating

100% UIS TESTED! 100% ΔVds TESTED!

TO-252





Schematic Diagram

V2.0

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCEP10N12K	NCEP10N12K	TO-252-2L	-	-	-

Absolute Maximum Ratings (T_C=25 ℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V _{DS}	120	V
Gate-Source Voltage	V _G S	±20	V
Drain Current-Continuous	I _D	I _D 65	
Drain Current-Continuous(T _C =100 °C)	I _D (100℃)	46	Α
Pulsed Drain Current	I _{DM}	260	Α
Maximum Power Dissipation	P _D	100	W
Derating factor		0.67	W/°C
Single pulse avalanche energy (Note 4)	E _{AS}	352	mJ
Operating Junction and Storage Temperature Range	T_{J}, T_{STG}	-55 To 175	$^{\circ}$

Thermal Characteristic

Thermal Resistance,Junction-to-Case	R _{θJC}	1.5	°C/W
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Electrical Characteristics (T_C=25 [°]C unless otherwise noted)

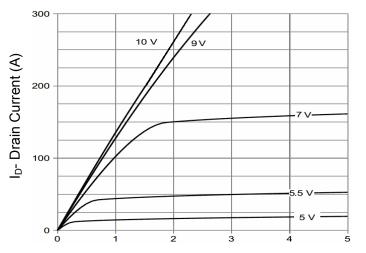
Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics				•		
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250μA 120			-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =120V,V _{GS} =0V	-	-	1	μA
Gate-Body Leakage Current	I _{GSS}	V_{GS} =±20 V , V_{DS} =0 V	-	-	±100	nA
On Characteristics (Note 3)			•			
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=250\mu A$	2.0	3.0	4.0	V
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =10V, I _D =35A	-	8.7	10.0	mΩ
Forward Transconductance	g FS	V_{DS} =5 V , I_D =35 A		60	-	S
Dynamic Characteristics (Note3)			•			
Input Capacitance	C _{lss}		-	3050	-	pF
Output Capacitance	C _{oss}	V_{DS} =60V, V_{GS} =0V, F=1.0MHz	-	280	-	pF
Reverse Transfer Capacitance	C _{rss}	F=1.UIVIHZ	-	22	-	pF
Switching Characteristics (Note 3)			•			
Turn-on Delay Time	t _{d(on)}		-	15	-	nS
Turn-on Rise Time	t _r	V_{DD} =60 V , I_{D} =35 A	-	10	-	nS
Turn-Off Delay Time	t _{d(off)}	V_{GS} =10 V , R_{G} =1.6 Ω	-	34	-	nS
Turn-Off Fall Time	t _f		-	8	-	nS
Total Gate Charge	Qg	V 00V/1 05A	-	53	-	nC
Gate-Source Charge	Q _{gs}	$V_{DS}=60V,I_{D}=35A,$	-	20	-	nC
Gate-Drain Charge	Q_{gd}	V _{GS} =10V	-	12.5	-	nC
Drain-Source Diode Characteristics			•	I.	L	
Diode Forward Voltage (Note 2)	V _{SD}	V _{GS} =0V,I _S =35A	-	-	1.2	V
Diode Forward Current	I _S		-	-	65	Α
Reverse Recovery Time	t _{rr}	$T_J = 25^{\circ}C, I_F = 35A$	-	60	-	nS
Reverse Recovery Charge	Qrr	$di/dt = 100A/\mu s^{(Note3)}$	-	106	-	nC

Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2%.
- 3. Guaranteed by design, not subject to production
- 4. EAS condition : Tj=25 $^{\circ}\text{C}$,V_DD=50V,V_G=10V,L=0.25mH,Rg=25 Ω

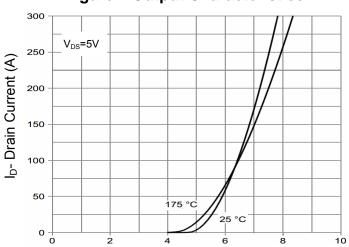


Typical Electrical and Thermal Characteristics



Vds Drain-Source Voltage (V)

Figure 1 Output Characteristics



Vgs Gate-Source Voltage (V)
Figure 2 Transfer Characteristics

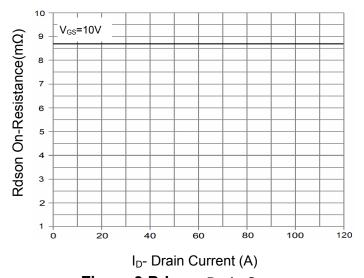


Figure 3 Rdson- Drain Current

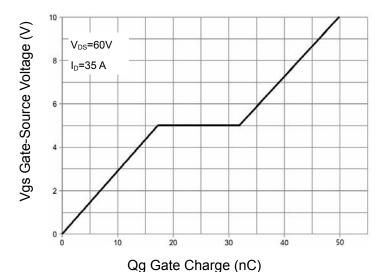


Figure 4 Gate Charge

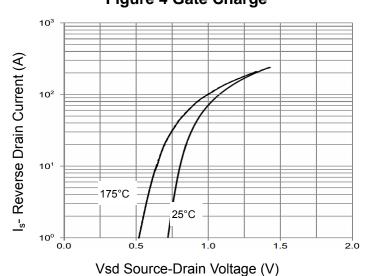
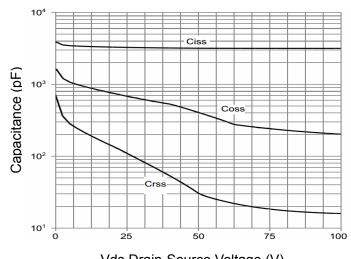


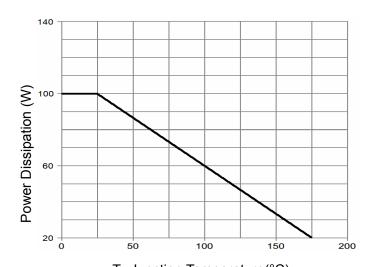
Figure 5 Source- Drain Diode Forward



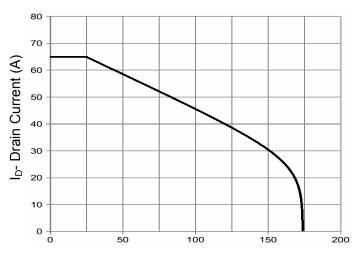
Vds Drain-Source Voltage (V)

Figure 6 Capacitance vs Vds





T_J-Junction Temperature(°C) **Figure 7 Power De-rating**



T_J-Junction Temperature (°C)

Figure 9 Current De-rating

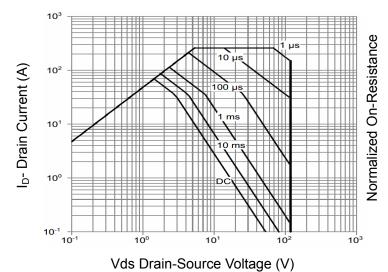
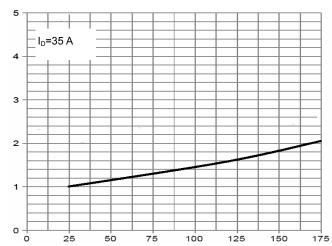
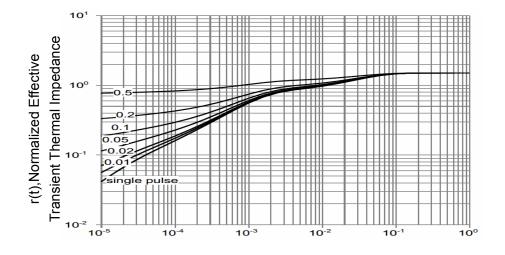


Figure 8 Safe Operation Area



 T_J -Junction Temperature(${}^{\circ}\mathbb{C}$)

Figure 10 Rdson-Junction Temperature



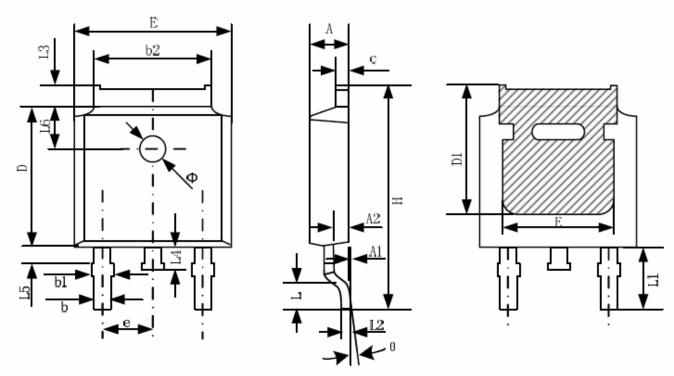
Square Wave Pluse Duration(sec)

Figure 11 Normalized Maximum Transient Thermal Impedance

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TO-252-2L Package Information



Cumahal	Dimensions	In Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
А	2.20	2.38	0.087	0.094	
A1	0.00	0.10	0.000	0.004	
A2	0.90	1.10	0.035	0.043	
b	0.72	0.85	0.028	0.033	
b1	0.72	0.90	0.028	0.035	
b2	5.13	5.46	0.202	0.215	
С	0.47	0.60	0.019	0.024	
D	6.00	6.20	0.236	0.244	
D1	5.25		0.207		
E	6.50	6.70	0.256	0.264	
E1	4.70		0.185		
e	2.19	2.39	0.086	0.094	
Н	9.80	10.40	0.386	0.409	
L	1.40	1.70	0.055	0.067	
L1	2.90	REF	0.114	4 REF	
L2	0.508	BSC	0.02	0 BSC	
L3	0.90	1.25	0.035	0.049	
L4	0.60	1.00	0.024	0.039	
L5	0.15	0.75	0.006	0.030	
L6	1.80	REF	0.07	REF	
Φ	1.20	1.40	0.047	0.055	
θ	0°	8°	0°	8°	



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